20 MHz to 6 GHz Gain Block

Description

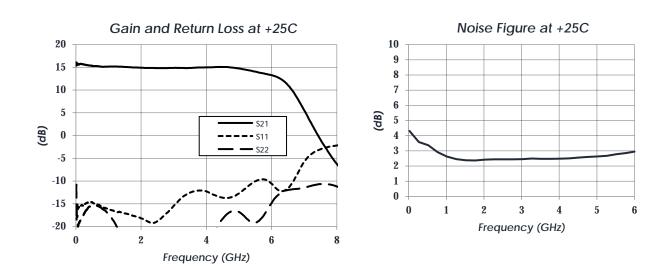
AM1016A is a high dynamic range cascadable gain block covering the 20 MHz to 6 GHz frequency range. It operates from a +3.3 VDC supply and exhibits a flat frequency response and high third order intercept performance while also providing excellent gain stability over the operating temperature range. With internal 50 Ω matching and packaged in a 3mm QFN or a shielded module, the AM1016A represents a compact total PCB footprint.

Functional Diagram



Features

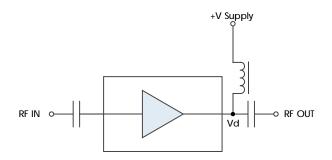
- 2.5 dB Noise Figure
- +30 dBm OIP3
- +18 dBm P1dB
- +19 dBm PSat
- +3.3V, 55 mA
- 3mm QFN Package
- -40C to +85C Operation
- Unconditionally Stable



Characteristic Performance

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20 MHz to 6 GHz Gain Block

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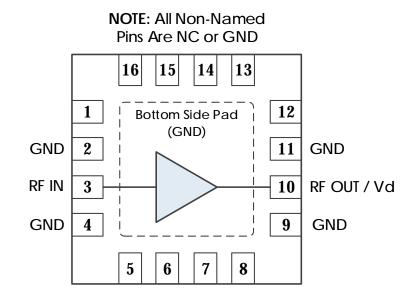
Revision History

Date	Revision Number	Notes
December 13, 2017	А	Initial Release
December 17, 2017	A1	Formatting Changes
August 2, 2019	2	Updated to Latest Datasheet Format. Min/Typ/Max Current Values Changed. RF-Shielded Module Information Added.
November 26, 2019	2A	Updated Description to include shielded module packaging



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Pin Layout and Definitions



Pin Number	Pin Name	Pin Function
1	NC	Not Connected*
2	GND	Ground – Common
3	RF IN	RF Input – 50 ohms – DC Coupled, External DC Block Required
4	GND	Ground - Common
5 - 8	NC	Not Connected*
9	GND	Ground – Common
10	RF OUT / Vd	RF Output and DC Power Input – 50 ohms – DC Coupled,
		External DC Block Required
11	GND	Ground - Common
12 - 16	NC	Not Connected*
Bottom Pad	GND	Ground – Common

*Note: NC pins may be grounded or left open.



20 MHz to 6 GHz Gain Block

Specifications

Absolute Maximum Ratings

	Minimum	Maximum
Device Voltage, Vd	0.0 V	+4.0 V
RF Input Power		+15 dBm
Operating Junction Temperature	-40 C	+150 C
Storage Temperature Range	-50 C	+150 C

Note: Any device operation beyond the Absolute Maximum Ratings may result in permanent damage to the device. The values listed in this table are extremes and do not imply functional operation of the device at these or any other conditions beyond what is listed under Recommended Operating Conditions. Any part subjected to conditions outside of what is recommended for an extended amount of time may suffer from reliability concerns.

Handling Information

	Minimum	Maximum
Storage Temperature Range (Recommended)	-50 C	+125 C
Moisture Sensitivity Level	MSL 3	



Atlanta Micro products are electrostatic sensitive.

Follow safe handling practices to avoid damage

Recommended Operating Conditions

	Minimum	Typical	Maximum
Supply Voltage, Vsupply	+3.0 V	+3.3 V	+3.8 V
Device Voltage, Vd	+2.7V	+3.0 V	+3.5 V
Operating Case Temperature	-40 C	+25 C	+85 C
Operating Junction Temperature	-40 C		+125 C

Thermal Information

	Thermal Resistance (°C / W)
Junction to Case Thermal Resistance (θ _{Jc})	137



20 MHz to 6 GHz Gain Block

DC Electrical Characteristics

(T = 25 °C unless otherwise specified)

Parameter	Testing Conditions	Minimum	Typical	Maximum
Device Voltage, Vd		+2.7 V	+3.0 V	+3.5 V
DC Supply Current	Vsupply = $+3.3$ V	50 mA	55 mA	70 mA
Power Dissipated	Vsupply = $+3.3$ V	0.17 W	0.18 W	0.23 W

RF Performance

(T = 25 °C unless otherwise specified)

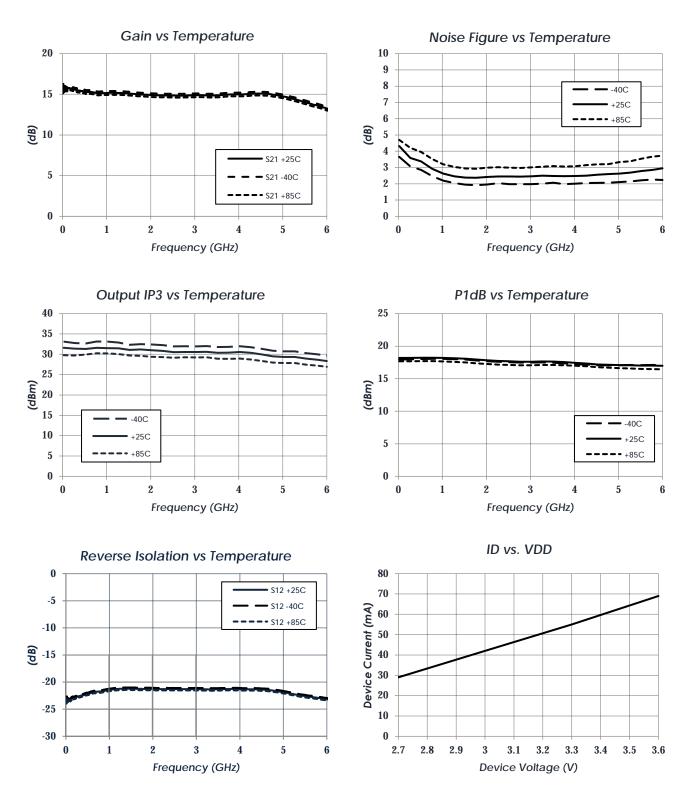
Parameter	Testing Conditions	Minimum	Typical	Maximum
Frequency Range		20 MHz		6 GHz
Gain	f = 3 GHz		15 dB	
Output IP3	f = 3 GHz		+30 dB	
Output P1dB	f = 3 GHz		+17 dB	
Noise Figure	f = 3 GHz		2.5 dB	



20 MHz to 6 GHz Gain Block

Typical Performance

(Vd = +3.0V, ID=55mA)



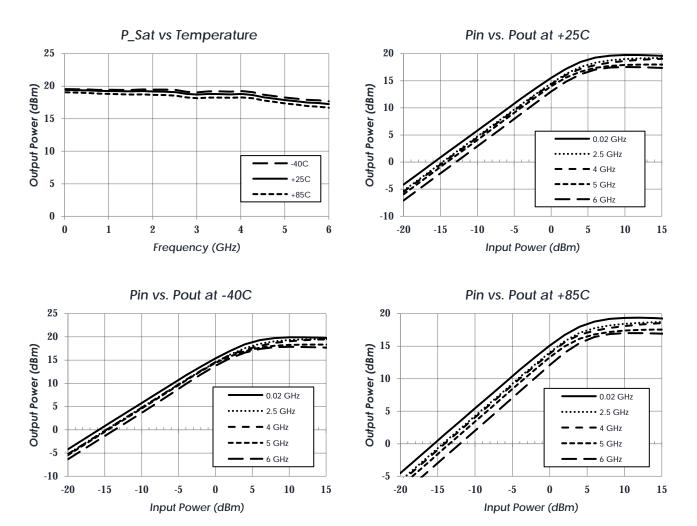
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20 MHz to 6 GHz Gain Block

Typical Performance (continued)

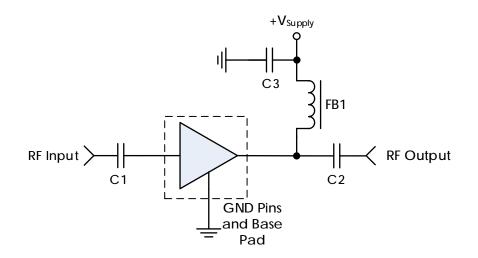
(Vd = +3.0V, ID=55mA)





20 MHz to 6 GHz Gain Block

Typical Application



Recommended Component List (or equivalent):

Part	Value	Part Number	Manufacturer
C1, C2	0.1 uF	0402BB104KW160	Passives Plus
C3	0.1 uF	GRM155R71C104KA88	Murata
FB1	-	MMZ1005A222E	TDK

Notes:

- 1. NC pins may be grounded or left open.
- 2. DC blocking capacitors should be high performance, low-loss, broadband capacitors for optimum performance.



20 MHz to 6 GHz Gain Block

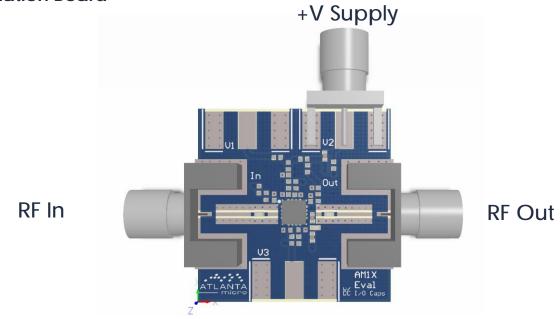
Part Ordering Details

Description	Part Number
3mm 16 Lead QFN	AM1016A
AM1016A Evaluation Board	AM1016A Eval
AM1016A in 0.95" x 1.13" x 0.6" RF-Shielded Module with	AM1016A-M
Integrated Bias Tee and Field Replaceable SMA Connectors	

Related Parts

Part Number				Description
AM1016B	20 MHz	to	6 GHz	+3.3V Gain Block
AM1018A	20 MHz	to	6 GHz	+3.3V Gain Block
AM1018B	20 MHz	to	6 GHz	+5.0V Gain Block
AM1018C	20 MHz	to	6 GHz	+5.0V Gain Block
AM1025B	20 MHz	to	3 GHz	+8.0V Gain Block (High P1dB)
AM1031C	20 MHz	to	8 GHz	+3.3V Gain Block
AM1063-1	DC	to	10 GHz	Gain Block
AM1064-1	DC	to	8 GHz	Gain Block
AM1085	DC	to	6 GHz	+5.0V Gain Block
AM1090	DC	to	6 GHz	+5.0V or +8.0V Gain Block

Evaluation Board

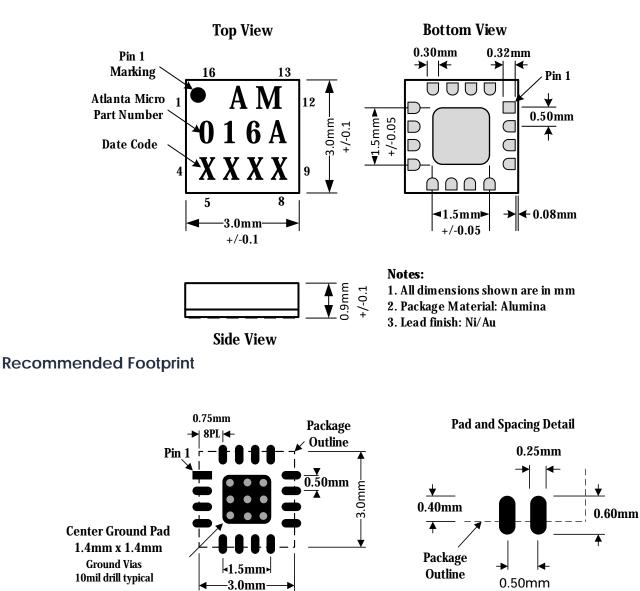




20 MHz to 6 GHz Gain Block

3mm 16 Lead QFN Details

Package Drawing



Apply solderpaste for approximately 2/3 coverage over ground pad to allow for flow

Recommend 0.08mm soldermask oversize beyond pad outlines



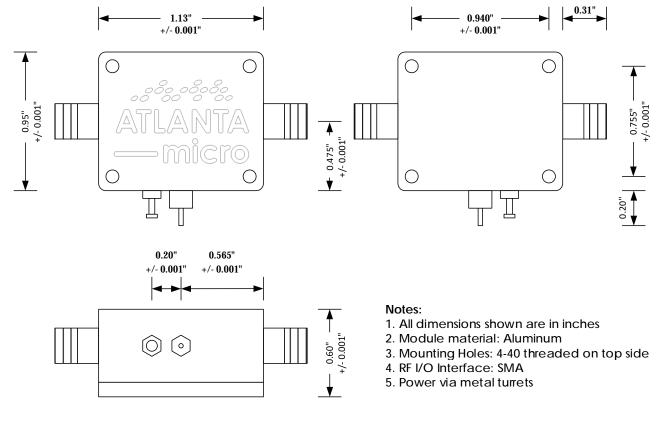
20 MHz to 6 GHz Gain Block

RF Shielded Module Details



Top View

Bottom View



Front View

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Substance List	Allowable Maximum Concentration
Lead (Pb)	<1000 PPM (0.1% by weight)
Mercury (Hg)	<1000 PPM (0.1% by weight)
Cadmium (Cd)	<75 PPM (0.0075% by weight)
Hexavalent Chromium (CrVI)	<1000 PPM (0.1% by weight)
Polybrominated Biphenyls (PBB)	<1000 PPM (0.1% by weight)
Polybrominated Diphenyl ethers (PBDE)	<1000 PPM (0.1% by weight)
Decabromodiphenyl Deca BDE	<1000 PPM (0.1% by weight)
Bis (2-ethylheyl) Phthalate (DEHP)	<1000 PPM (0.1% by weight)
Butyl Benzyl Phthalate (BBP)	<1000 PPM (0.1% by weight)
Dibutyl Phthalate (DBP)	<1000 PPM (0.1% by weight)
Diisobutyl Phthalate (DIBP)	<1000 PPM (0.1% by weight)

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